

1.4 Primary electrical characteristics. Primary electrical characteristics are as shown in maximum and primary test ratings (see 3.8) herein and as follows:

- a.  $11 \text{ V dc} \leq V_Z \leq 200 \text{ V dc}$ .
- b. 1N962B-1 through 1N992B-1 are 5 percent voltage tolerance.
- c. 1N962C-1 through 1N992C-1 are 2 percent voltage tolerance.
- d. 1N962D-1 through 1N992D-1 are 1 percent voltage tolerance.

Thermal resistance:

$R_{\theta JL} = 250^\circ\text{C/W}$  maximum at  $L = .375$  inch (9.53 mm) (DO-35).

$R_{\theta JEC} = 100^\circ\text{C/W}$  maximum. Junction to end-caps (DO-213AA).

$R_{\theta JA}(\text{PCB}) = 300^\circ\text{C/W}$  junction to ambient including PCB see note (1).

- \* (1) See figure 5, figure 6, and figure 7 for derating curves.  $T_A = +75^\circ\text{C}$  for both axial and MELF (Metal Electrical Leadless Face) (US) on printed circuit board (PCB), PCB = FR4 .0625 inch (1.59 mm) 1-layer 1-Oz Cu, horizontal, still air, pads (US) = .067 inch (1.70 mm) x .105 inch (2.67 mm); pads (axial) = .092 inch (2.34 mm) diameter, strip = .030 inch (0.762 mm) x 1 inch (25.4 mm) long, axial lead length  $L \leq .187$  inch ( $\leq 4.76$  mm);  $R_{\theta JA}(\text{PCB})$  with a defined thermal resistance condition included is measured at  $I_Z =$  as defined in the electrical characteristics tolerance table herein.
- \* (2) For thermal impedance curves see figure 8, figure 9, and figure 10.

\* 1.5 Part or Identifying Number (PIN). The PIN is in accordance with MIL-PRF-19500, and as specified herein. See 6.6 for PIN construction example and 6.7 for a list of available PINs.

\* 1.5.1 JAN certification mark and quality level designators.

\* 1.5.1.1 Quality level designators for encapsulated devices. The quality level designators for encapsulated devices that are applicable for this specification sheet from the lowest to the highest level are as follows: "JAN", "JANTX", "JANTXV", and "JANS".

\* 1.5.1.2 Quality level designators for unencapsulated devices (die). The quality level designators for unencapsulated devices (die) that are applicable for this specification sheet from the lowest to the highest level are as follows: "JANH" and "JANK".

\* 1.5.2 Device type. The designation system for the device types of semiconductor covered by this specification sheet are as follows.

\* 1.5.2.1 First number and first letter symbols. The semiconductors of this specification sheet use the first number and letter symbols "1N".

\* 1.5.2.2 Second number symbols. The second number symbols for the semiconductor covered by this specification sheet are as follows: "962", "963", "964", "965", "966", "967", "968", "969", "970", "971", "972", "973", "974", "975", "976", "977", "978", "979", "980", "981", "982", "983", "984", "985", "986", "987", "988", "989", "990", "991", and "992".

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\* 1.5.3 Suffix symbols. The following suffix symbol are incorporated in the PIN as applicable.

\* 1.5.3.1 First suffix symbol. The first suffix letter "B" indicates that the diodes are 5 percent voltage tolerance. The first suffix letter "C" indicates that the diodes are 2 percent voltage tolerance. The first suffix letter "C" indicates that the diodes are 1 percent voltage tolerance.

\* 1.5.3.2 Following suffix symbols. The following suffix symbols are incorporated in the PIN for this specification sheet:

-1	Indicates an axial through hole DO-35 metallurgical bonded double plug construction. (see <a href="#">figure 1</a> ).
UR-1	Indicates a surface mount DO-213AA using a metallurgical bonded double plug construction. (see <a href="#">figure 2</a> )

\* 1.5.4 Lead finish. The lead finishes applicable to this specification sheet are listed on [QML-19500](#).

\* 1.5.5 Die identifiers for unencapsulated devices (manufacturers and critical interface identifiers). The manufacturer die identifiers that are applicable for this specification sheet are "A" and "B".

## 2. APPLICABLE DOCUMENTS

2.1 General. The documents listed in this section are specified in sections 3 and 4 of this specification. This section does not include documents cited in other sections of this specification or recommended for additional information or as examples. While every effort has been made to ensure the completeness of this list, document users are cautioned that they must meet all specified requirements of documents cited in sections 3 and 4 of this specification, whether or not they are listed.

### 2.2 Government documents.

2.2.1 Specifications, standards, and handbooks. The following specifications, standards, and handbooks form a part of this document to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

#### DEPARTMENT OF DEFENSE SPECIFICATIONS

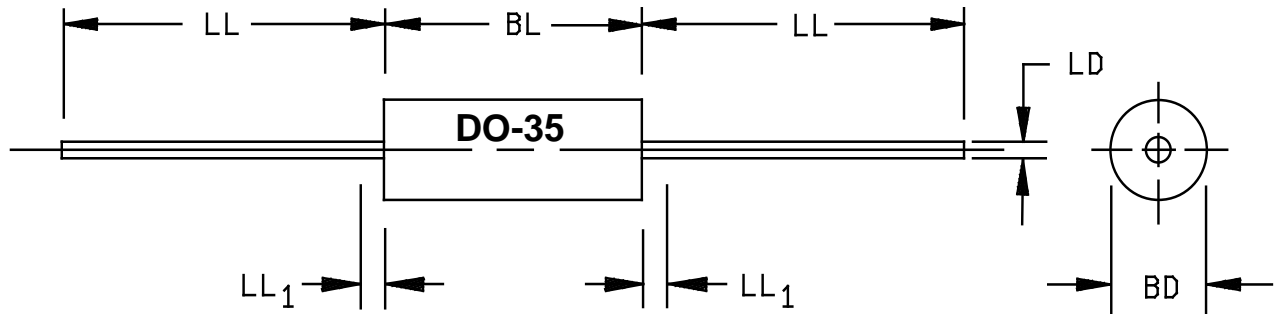
[MIL-PRF-19500](#) - Semiconductor Devices, General Specification for.

#### DEPARTMENT OF DEFENSE STANDARDS

[MIL-STD-750](#) - Test Methods for Semiconductor Devices.

(Copies of these documents are available online at <http://quicksearch.dla.mil>.)

2.3 Order of precedence. Unless otherwise noted herein or in the contract, in the event of a conflict between the text of this document and the references cited herein, the text of this document takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

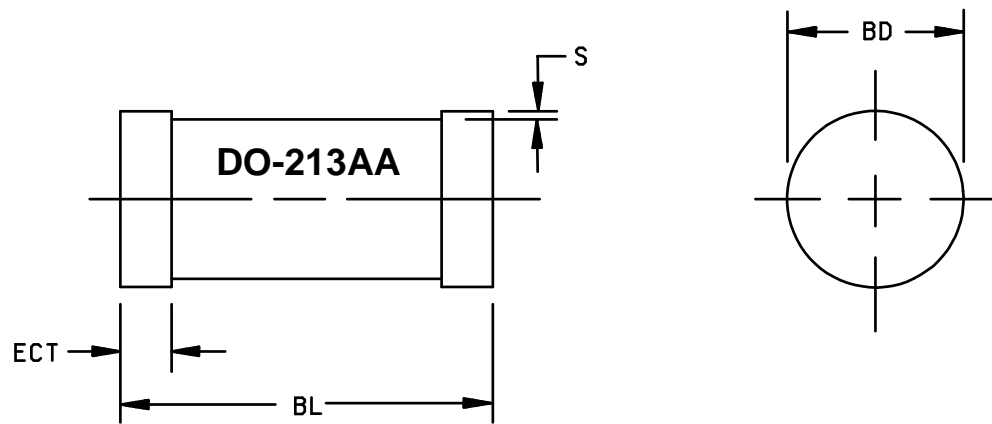


Symbol	Dimensions				Notes
	Inches		Millimeters		
	Min	Max	Min	Max	
BD	.055	.090	1.40	2.29	3
BL	.120	.200	3.05	5.08	3
LD	.018	.022	0.46	0.56	
LL	1.000	1.500	25.40	38.10	
LL <sub>1</sub>		.050		1.27	4

## NOTES:

1. Dimensions are in inches.
2. Millimeters are given for general information only.
3. Package contour optional within BD and length BL. Heat slugs, if any, shall be included within this cylinder but shall not be subject to minimum limit of LD. The BL dimension shall include the entire body including slugs (new note).
4. Within LL<sub>1</sub> lead diameter may vary to allow for flash, lead finish build-up, and minor irregularities other than heat slugs.
5. In accordance with ASME Y14.5M, diameters are equivalent to  $\Phi X$  symbology.

FIGURE 1. Physical dimensions for types 1N962B-1 through 1N992B-1, 1N962C-1 through 1N992C-1, 1N962D-1 through 1N992D-1 (DO-35).

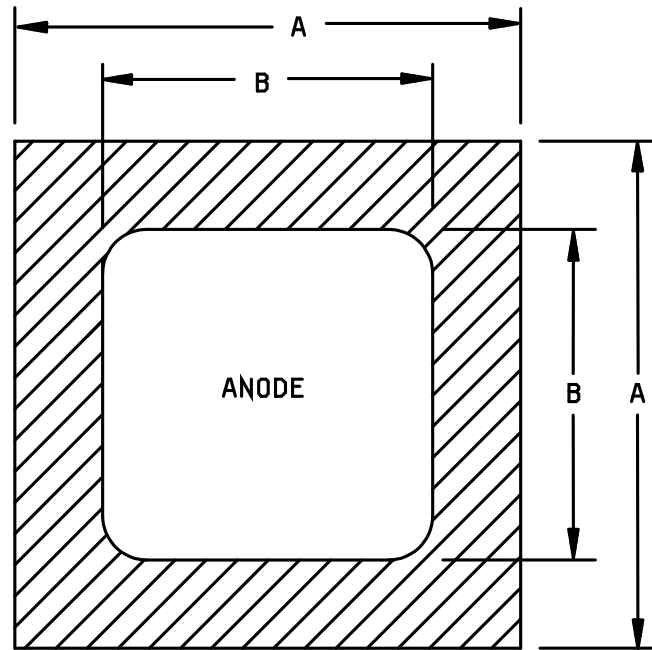


Symbol	Dimensions			
	Inches		Millimeters	
	Min	Max	Min	Max
BL	.130	.146	3.30	3.70
BD	.063	.067	1.60	1.70
ECT	.016	.022	0.41	0.55
S	.001 min		0.03 min	

## NOTES:

1. Dimensions are in inches.
2. Millimeters are given for general information only.
- \* 3. Referencing to dimension S, minimum clearance of glass body to mounting surface on all orientations.
4. In accordance with ASME Y14.5M, diameters are equivalent to  $\Phi X$  symbology.

FIGURE 2. Physical dimensions for types 1N962BUR-1 through 1N992BUR-1, 1N962CUR-1 through 1N992CUR-1, 1N962DUR-1 through 1N992DUR-1 (DO-213AA).



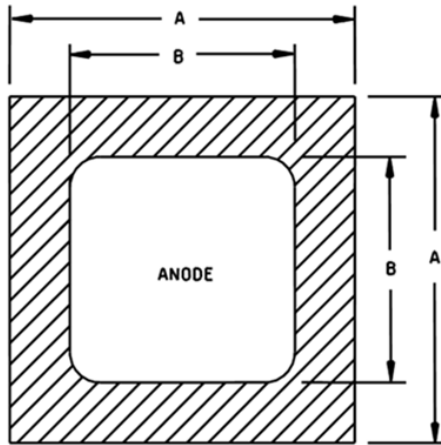
BACKSIDE IS CATHODE

Ltr	Dimensions											
	JANHCA				JANHCB				JANHCC, JANKCC			
	Inches		Millimeters		Inches		Millimeters		Inches		Millimeters	
	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max
A	.021	.025	0.53	0.63	.024	.028	0.61	0.71	.019	.023	0.48	0.58
B	.013	.017	0.33	0.43	.017	.021	0.43	0.53	.013	.017	0.33	0.43

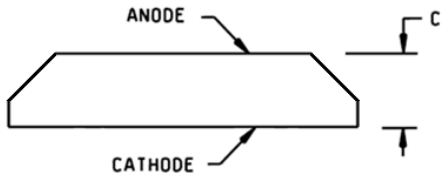
NOTES:

1. Dimensions are in inches.
2. Millimeters are given for general information only.
3. The physical characteristics of the die thickness are  $.010 \pm .002$  ( $0.25 \text{ mm} \pm 0.051$ ).  
Metallization:  
top = (anode) - AL,  
back: (cathode) - AU,  
Minimum AL thickness = 12,000 Å for JANHCA, 40,000 Å for JANHCB, and 25,000 Å for JANHCC and KCC.  
Minimum AU thickness = 3,000 Å for JANHCA, and 5,000 Å for JANHCB, and 4,000 Å for JANHCC and KCC.
4. Circuit layout data: For zener operation, cathode must be operated positive with respect to anode.
5. Requirements in accordance with appendix G of MIL-PRF-19500, are performed in a TO-5 package (see 6.5).

FIGURE 3. Physical dimensions (JANHCA, JANHCB, JANHCC, and JANKCC die dimensions).



BACKSIDE IS CATHODE



Ltr	Dimensions JANHCD and JANKCD			
	Inches		Millimeters	
	Min	Max	Min	Max
A	.019	.023	0.483	0.584
B	.011	.015	0.279	0.381
C	.008	.012	0.203	0.305

NOTES:

1. Dimensions are in inches.
2. Millimeter equivalents are given for general information only.
3. The die thickness is .010 (0.25 mm)  $\pm$  .002 inches ( $\pm$ 0.05 mm).  
 Anode metallization: Al, thickness = 34,000 Å minimum;  
 Cathode metallization: Au, thickness = 3,600 Å minimum.

\* FIGURE 4. Physical dimensions (JANHCD, and JANKCD die dimensions).

### 3. REQUIREMENTS

3.1 General. The individual item requirements shall be as specified in [MIL-PRF-19500](#) and as modified herein.

3.2 Qualification. Devices furnished under this specification shall be products that are manufactured by a manufacturer authorized by the qualifying activity for listing on the applicable qualified manufacturer's list (QML) before contract award (see [4.2](#) and [6.3](#)).

3.3 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in [MIL-PRF-19500](#), and as follows.

EC - - - - - end-caps.

R $\theta$ JA(PCB) - - - thermal resistance junction to ambient, with a defined printed circuit board mounting.

R $\theta$ JBB - - - - - Thermal resistance junction to burn-in board.

\* 3.4 Interface and physical dimensions. The interface and physical dimensions shall be specified in [MIL-PRF-19500](#) and figures [1](#) and [2](#) (similar to DO-35 and DO-213AA), and [figure 3](#) and [figure 4](#) (die) herein.

3.4.1 Lead finish. Lead finish shall be solderable in accordance with [MIL-PRF-19500](#), [MIL-STD-750](#), and herein. Where a choice of lead finish is desired, it shall be specified in the acquisition document (see [6.2](#)).

3.4.2 Diode construction. All devices shall be metallurgically bonded double plug construction in accordance with the requirements of category I, II, or III (see [MIL-PRF-19500](#)).

3.5 Marking. Marking shall be in accordance with [MIL-PRF-19500](#). Manufacturer's identification and date code shall be marked on the devices. Initial container package marking shall be in accordance with [MIL-PRF-19500](#). The polarity shall be indicated with a contrasting color band to denote the cathode end. The prefixes JAN, JANTX, and JANTXV can be abbreviated as J, JX, and JV, respectively. (example: The part number can be reduced to J962B1) No color coding shall be permitted for part numbering.

3.5.1 Marking of UR devices. For 'UR' version devices only, all marking, except polarity may be omitted from the body, but shall be retained on the initial container. Polarity marking of 'UR' devices shall consist as a minimum, a band or 3 contrasting dots around the periphery of the cathode.

3.6 Selection of tight tolerance devices. The C and D suffix devices shall be selected from JAN, JANTX, or JANTXV devices, which have successfully completed all applicable screening, and groups A, B, and C testing as 5 percent tolerance devices. All sublots of C and D suffix devices shall pass [table I](#), subgroup 2, at tightened tolerances. Tighter tolerances for mounting clip temperature shall be maintained for reference purpose to establish correlation. For C and D tolerance levels,  $T_L = +25^{\circ}\text{C} \pm 2^{\circ}\text{C}$  at .375 inch (9.53 mm) from body or equivalent.

3.7 Electrical performance characteristics. Unless otherwise specified herein, the electrical performance characteristics are as specified in [1.3](#), [1.4](#), and [table I](#), [table II](#), and [table III](#).

3.8 Electrical test requirements. The electrical test requirements shall be the subgroups specified in [table I](#) herein.

3.9 Maximum and primary test ratings. Maximum and primary test ratings for voltage regulator diodes are specified in [table IV](#) herein.

3.10 Workmanship. Semiconductor devices shall be processed in such a manner as to be uniform in quality and shall be free from other defects that will affect life, serviceability, or appearance.

## 4. VERIFICATION

4.1 Classification of inspections. The inspection requirements specified herein are classified as follows:

- a. Qualification inspection (see 4.2).
- b. Screening (see 4.3).
- c. Conformance inspection (see 4.4).

4.2 Qualification inspection. Qualification inspection shall be in accordance with MIL-PRF-19500 and as specified herein.

4.2.1 Group E qualification. Group E inspection shall be performed for qualification or re-qualification only. In case qualification was awarded to a prior revision of the specification sheet that did not request the performance of table II tests, the tests specified in table II herein that were not performed in the prior revision shall be performed on the first inspection lot of this revision to maintain qualification.

4.2.2 JANHC and JANKC devices. JANHC and JANKC devices shall be qualified in accordance with appendix G of MIL-PRF-19500.

4.2.3 Construction verification. Cross sectional photos from three devices shall be submitted in the qualification report.

\* 4.3 Screening (JAN, JANTX, and JANTXV levels only). Screening shall be in accordance with table E-IV of MIL-PRF-19500 and as specified herein. The following measurements shall be made in accordance with table I herein. Devices that exceed the limits of table I herein shall not be acceptable.

Screen	Measurement
	JANTX and JANTXV levels
3a	Temperature cycling
(1) 3c	Thermal impedance (see 4.3.2)
7a	Not required
7b	Optional
9	Not required
11	$I_{R1}$ and $V_Z$
12	See 4.3.3
(2) 13	$\Delta I_{R1} \leq 100$ percent of initial reading or 50 nA dc, whichever is greater. $\Delta V_Z \leq \pm 2$ percent initial reading. Subgroup 2 of table I herein.
14a	Not required
(3) 14b	Required

- (1) Thermal impedance shall be performed any time after sealing provided temperature cycling is performed in accordance with MIL-PRF-19500, screen 3a; JANTX and JANTXV levels do not need to be repeated in screening requirements.
- (2) PDA = 5 percent for screen 13 applies to  $\Delta I_{R1}$  and  $\Delta V_Z$ . Thermal impedance ( $Z_{\theta JX}$ ) is not required in screen 13.
- (3) For clear glass diodes, the hermetic seal (gross leak) may be performed at anytime after temperature cycling.



4.3.1 Screening (JANHC and JANKC). Screening of JANHC and JANKC die shall be in accordance with appendix G of [MIL-PRF-19500](#).

4.3.1.1 JAN testing. JAN level product will have temperature cycling and thermal impedance testing performed in accordance with [MIL-PRF-19500](#), JANTX level screening level requirements.

4.3.2 Thermal impedance. The thermal impedance measurements shall be performed in accordance with method 3101 or 4081, as applicable, of MIL-STD-750 using the guidelines in that method for determining  $I_M$ ,  $I_H$ ,  $t_H$ ,  $t_{MD}$  (and  $V_C$  where appropriate). Measurement delay time  $t_{MD} = 70 \mu s$  max. (See [table II](#), subgroup 4).

4.3.3 Power burn-in conditions. Power burn-in conditions are as follows:  $I_{ZM}$  (min) = column 8 of [table IV](#);  $T_A = 75^\circ C$  maximum. Test conditions in accordance with method 1038 of [MIL-STD-750](#), condition B (see [4.5.6](#)). Adjust  $I_Z$  or  $T_A$  to achieve the required  $T_J$ .  $T_J = 125^\circ C$  minimum. With approval of the qualifying activity and preparing activity, alternate burn-in criteria (hours, bias conditions,  $T_J$  mounting conditions) may be used for JANTX and JANTXV quality levels. A justification demonstrating equivalence is required. In addition, the manufacturing site's burn-in data and performance history will be essential criteria for burn-in modification approval.

4.4 Conformance inspection. Conformance inspection shall be in accordance with [MIL-PRF-19500](#) and as specified herein. Group A inspection shall be performed on each subplot.

4.4.1 Group A inspection. Group A inspection shall be conducted in accordance with [MIL-PRF-19500](#), and [table I](#) herein.

4.4.2 Group B inspection. Group B inspection shall be conducted in accordance with the conditions specified for subgroup testing in appendix E, table E-VIb (JAN, JANTX, and JANTXV) of [MIL-PRF-19500](#) and [4.4.2.1](#) herein. Electrical measurements (end-points) shall be in accordance with the applicable inspections of [table III](#) herein.

4.4.2.1 Group B inspection, appendix E, table E-VIb (JAN, JANTX and JANTXV) of [MIL-PRF-19500](#).

Subgroup	Method	Condition
B2	1056	$0^\circ C$ to $+100^\circ C$ , 10 cycles.
B2	1051	$-55^\circ C$ to $+175^\circ C$ , 25 cycles.
B2	4066	See <a href="#">4.5.1</a> .
B3	1027	$I_{Z(min)}$ = column 8 of <a href="#">table IV</a> . Adjust $I_Z$ or $T_A$ to achieve $T_J = 150^\circ C$ minimum (see <a href="#">4.5.6</a> ).
B4	2101	Decap analysis, scribe and break only.

4.4.3 Group C inspection. Group C inspection shall be conducted in accordance with the conditions specified for subgroup testing in appendix E, table E-VII of MIL-PRF-19500, and as follows. Electrical measurements (end-points) shall be in accordance with table III herein.

<u>Subgroup</u>	<u>Method</u>	<u>Condition</u>
C2	1056	0°C to +100°C, 10 cycles.
* C2	1051	-55°C to +175°C, 25 cycles.
C2	2036	Tension: Test condition A; weight = 10 pounds, t = 15 seconds. Lead fatigue: Test condition E. (Lead fatigue is not required for UR-1 suffix devices)
C2	1071	Test condition E.
C3		Not applicable.
C5	4081	See 4.3.2 herein.
C6	1027	I <sub>Z(min)</sub> = column 8 of table IV. Adjust I <sub>Z</sub> or T <sub>A</sub> to achieve T <sub>J</sub> = 150°C minimum (see 4.5.6).
C7		Not applicable.
C8	4071	I <sub>Z</sub> = column 5 of table IV; T <sub>1</sub> = +25°C ±5°C, T <sub>2</sub> = +125°C ±5°C. (Maximum limit in accordance with column 14 of table IV). Sample size = 22, c = 0. (See 4.5.4.)

4.4.4 Group E inspection. Group E inspection shall be conducted in accordance with appendix E, table E-IX of MIL-PRF-19500 and table II herein. Electrical measurements (end-points) shall be in accordance with the applicable inspections of table III herein.

4.5 Methods of inspection. Methods of inspection shall be as specified in the appropriate tables and as follows.

4.5.1 Surge current (I<sub>ZSM</sub>). The peak currents shown in column 10 of table IV shall be applied in the reverse direction and these shall be imposed on the current (I<sub>Z</sub> = I<sub>Z1</sub>) (column 5 of table IV) a total of 5 surges at 1-minute intervals. Each individual surge shall be one-half square-wave-pulse of one one-hundred twenty second duration or an equivalent one-half sine wave with the same effective rms current.

4.5.2 Regulator voltage measurements. The test current shall be applied until thermal equilibrium is attained (90 seconds minimum) prior to reading the breakdown voltage. For this test, the diode shall be suspended by its leads with mounting clips whose inside edge is located at .375 inch (9.53 mm) from the body (UR version = 0 lead length) and the mounting clips shall be maintained at a temperature of +25°C +8°C, and -2°C. This measurement may be performed after a shorter time following application of the test current than that which provides thermal equilibrium if correlation to stabilized readings can be established to the satisfaction of the Government.

4.5.3 Voltage regulation V<sub>Z(reg)</sub>. Voltage regulation shall be determined by the difference of the regulator voltage measured at different currents as specified in table I, subgroup 7 herein. Both tests shall be performed at thermal equilibrium. This ΔV<sub>Z</sub> shall not exceed column 9 of table IV.

4.5.4 Temperature coefficient of regulator voltage ( $\alpha V_Z$ ). The device shall be temperature stabilized with current applied prior to reading regulator voltage at the specified ambient temperature as specified in 4.4.3, subgroup C8.

4.5.5 Scope display evaluation. Scope display evaluation shall be stable in accordance with method 4023 of MIL-STD-750, condition A. Scope display may be performed on ATE (automatic test equipment) for screening only with the approval of the qualifying activity. Scope display in table I, subgroup 4 shall be performed on a scope. The reverse current over the knee shall be 500  $\mu$ A peak.

4.5.6 Free air burn-in and life tests. The use of a current limiting or ballast resistor is permitted provided that each DUT still sees as a minimum the  $I_{Z(min)}$  described in 4.3.3 and that the minimum applied voltage, where applicable, is maintained through-out the burn-in period. Use method 3100 of MIL-STD-750 to measure  $T_J$ .

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\* TABLE I. Group A inspection.

Inspection <u>1/</u>	MIL-STD-750		Symbol	Limits <u>2/</u>		Unit
	Method	Conditions		Min	Max	
<u>Subgroup 1</u>						
Visual and mechanical examination	2071					
<u>Subgroup 2</u>						
Thermal impedance <u>3/</u>	3101	See 4.3.2	$Z_{\theta JX}$			°C/W
Forward voltage	4011	$I_F = 200$ mA dc.	$V_F$			V dc
1N962 - 1N985 <u>4/</u> 1N986 - 1N992 <u>4/</u>					1.1 1.3	
Reverse current	4016	DC method, $V_R =$ column 11 of <a href="#">table IV.</a>	$I_{R1}$		Col. 12	μA dc
Regulator voltage	4022	$I_{Z1} =$ column 5 of <a href="#">table IV.</a> , see 4.5.2	$V_Z$	Col. 3	Col. 4	V dc
Thermal impedance	3101	See 4.3.2	$Z_{\theta JX}$			°C/W
<u>Subgroup 3</u>						
High temperature operation		$T_A = 150^\circ\text{C}$				
Reverse current	4016	DC method, $V_R =$ column 11 of <a href="#">table IV.</a>	$I_{R2}$		Col. 13	μA dc
<u>Subgroup 4</u>						
Small-signal reverse breakdown impedance	4051	$I_Z =$ column 5 of <a href="#">table IV.</a> $I_{SIG} = 10$ percent of $I_Z$ rms.	$Z_Z$		Col. 6	ohm
Small-signal reverse breakdown impedance	4051	$I_{ZK} = 250$ μA dc, $I_{SIG} = 25$ μA rms.	$Z_{ZK}$		Col. 7	ohm
Scope display	4023	See 4.5.5, $n = 116$ , $c = 0$ .				

See footnotes at end of table.

\* TABLE I. Group A inspection - Continued.

Inspection <u>1/</u>	MIL-STD-750		Symbol	Limits <u>2/</u>		Unit
	Method	Conditions		Min	Max	
<u>Subgroups 5</u> Not applicable <u>Subgroup 6</u> Surge Electrical measurements <u>Subgroup 7</u> Voltage regulation (see <a href="#">4.5.3</a> )	4066	Condition B, See <a href="#">4.5.1</a>  See <a href="#">table III</a> , steps 1, 3, and 4.  I <sub>Z</sub> = 10 percent of column 8 of <a href="#">table IV</a> (current 1). I <sub>Z</sub> = 50 percent of column 8 of <a href="#">table IV</a> (current 2).	ΔV <sub>Z</sub> (reg)		Col. 9	V dc

1/ For sampling plan, see [MIL-PRF-19500](#).

2/ Column references are to [table IV](#).

3/ For end-point measurements, this test is required for the following subgroups:

Group B, subgroups 2 and 3 (JAN, JANTX, JANTXV).

Group C, subgroups 2 and 6.

Group E, subgroup 1.

4/ Applies to all suffix versions.

TABLE II. Group E inspection qualification and requalification (all product assurance levels).

Inspection 1/	MIL-STD-750		Qualification conformance inspection (sampling plan)
	Method	Conditions	
<u>Subgroup 1</u> Temperature cycling Electrical measurements	1051	500 cycles See <a href="#">table III</a> , steps 1, 2, 3, 4, and 5	45 devices, c = 0
<u>Subgroup 2</u> Intermittent life Electrical measurements	1037	6,000 cycles. I <sub>Z</sub> = column 8 of <a href="#">table IV</a> See <a href="#">table III</a> , steps 2, 3, 4, and 5	45 devices, c = 0
<u>Subgroup 4</u> Thermal impedance curve		See <a href="#">MIL-PRF-19500</a>	
<u>Subgroups 5 and 6</u> Not applicable			
<u>Subgroup 9</u> Resistance to glass cracking	1057	Condition B. Cool down after solder immersion is permitted. Test until failure occurs on all devices with the chosen sample or to a maximum of 25 cycles, whichever comes first	n = 45

1/ A separate sample may be pulled for each test.

TABLE III. Group B, C, and E electrical and delta end-point measurements. 1/ 2/ 3/

Step	Inspection	MIL-STD-750		Symbol	Limits		Unit
		Method	Conditions		Min	Max	
1.	Reverse current	4016	DC method; $V_R$ = column 11 of table IV.	$I_{R1}$		Column 12 of table IV	$\mu A$ dc
2.	Reverse current	4016	DC method; $V_R$ = column 11 of table IV.	$I_{R3}$		2	$\mu A$ dc
3.	Regulator voltage (see 4.5.2)	4022	$I_{Z1}$ = column 5 of table IV.	$V_Z$	Column 3 of table IV	Column 4 of table IV	V dc
4.	Small-signal breakdown impedance	4051	$I_{Z1}$ = column 5 of table IV. $I_{SIG}$ = 10 percent of $I_Z$ rms	$Z_{ZT}$		Column 6 of table IV	Ohms
5.	Thermal impedance	3101	See 4.3.2	$\Delta Z_{\theta JX}$		10 percent of initial value max.	$^{\circ}C/W$

- 1/ The electrical measurements for table VIb of MIL-PRF-19500 are as follows:
- Subgroup 2, see table III herein, steps 1, 3, 4, and 5.
  - Subgroups 3 and 6, see table III herein, steps 2, 3, and 4.
- 2/ The electrical measurements for table VII of MIL-PRF-19500 are as follows:
- Subgroup 2, see table III herein, steps 1, 3, 4, and 5.
  - Subgroup 6, see table III herein, steps 2, 3, and 4.
- 3/ The electrical measurements for table IX of MIL-PRF-19500 are as follows:
- Subgroup 1, see table III herein, steps 1, 2, 3, 4, and 5.
  - Subgroup 2, see table III herein, steps 2, 3, 4, and 5.

TABLE IV. Electrical characteristics (5 percent tolerance diodes).

Col 1	Col 2	Col 3	Col 4	Col 5	Col 6	Col 7	Col 8	Col 9	Col 10	Col 11	Col 12	Col 13	Col 14
Type	VZ nom	VZ min	VZ max	I <sub>Z1</sub>	ZZ	ZZK	I <sub>ZM</sub>	ΔVZ	I <sub>ZSM</sub>	V <sub>R</sub>	I <sub>R1</sub> at T <sub>A</sub> = +25°C V <sub>R</sub> = col 11	I <sub>R2</sub> at T <sub>A</sub> = +150°C V <sub>R</sub> = col 11	αVZ
	Volts	Volts	Volts	mA	ohms	ohms	mA	Volts	mA	Volts	μA	μA	%/°C
1N962B-1	11	10.45	11.55	11.5	9.5	700	35	0.50	590	8.4	1.0	10	+0.073
1N963B-1	12	11.40	12.60	10.5	11.5	700	32	0.55	540	9.1	1.0	10	+0.076
1N964B-1	13	12.35	13.65	9.5	13.0	700	30	0.60	500	9.9	0.5	10	+0.079
1N965B-1	15	14.25	15.75	8.5	16.0	700	26	0.70	433	11	0.5	10	+0.082
1N966B-1	16	15.20	16.80	7.8	17.0	700	25	0.75	406	12	0.5	10	+0.083
1N967B-1	18	17.10	18.90	7.0	21	750	21	0.85	361	14	0.5	10	+0.085
1N968B-1	20	19.0	21.0	6.2	25	750	19	0.95	325	15	0.5	10	+0.086
1N969B-1	22	20.9	23.1	5.6	29	750	17	1.05	295	17	0.5	10	+0.087
1N970B-1	24	22.8	25.2	5.2	33	750	16	1.15	271	18	0.5	10	+0.088
1N971B-1	27	25.7	28.3	4.6	41	750	14	1.30	240	21	0.5	10	+0.090
1N972B-1	30	28.5	31.5	4.2	49	1000	13	1.45	216	23	0.5	10	+0.091
1N973B-1	33	31.4	34.6	3.8	58	1000	12	1.60	197	25	0.5	10	+0.092
1N974B-1	36	34.2	37.8	3.4	70	1000	11	1.75	180	27	0.5	10	+0.093
1N975B-1	39	37.1	40.9	3.2	80	1000	9.1	1.90	166	30	0.5	10	+0.094
1N976B-1	43	40.9	45.1	3.0	93	1000	8.8	2.10	151	33	0.5	10	+0.095
1N977B-1	47	44.7	49.3	2.7	105	1500	7.9	2.25	138	36	0.5	10	+0.095
1N978B-1	51	48.5	53.5	2.5	125	1500	7.4	2.5	127	39	0.5	10	+0.096
1N979B-1	56	53.2	58.8	2.2	150	2000	6.9	2.7	116	43	0.5	10	+0.096
1N980B-1	62	58.9	65.1	2.0	185	2000	6.0	2.9	105	47	0.5	10	+0.097
1N981B-1	68	64.6	71.4	1.8	230	2000	5.5	3.2	95	52	0.5	10	+0.097
1N982B-1	75	71.3	78.7	1.7	270	2000	5.1	3.4	86	56	0.5	10	+0.098
1N983B-1	82	77.9	86.1	1.5	330	3000	4.6	3.8	79	62	0.5	10	+0.098
1N984B-1	91	86.5	95.5	1.4	400	3000	4.2	4.2	71	69	0.5	10	+0.099
1N985B-1	100	95.0	105.0	1.3	500	3000	3.7	4.4	65	76	0.5	10	+0.110
1N986B-1	110	104.5	115.5	1.1	750	4000	3.3	4.8	59	84	0.5	10	+0.110
1N987B-1	120	114.0	126.0	1.0	900	4500	3.1	5.2	54	91	0.5	10	+0.110
1N988B-1	130	123.5	136.5	0.95	1100	5000	2.7	5.6	50	99	0.5	10	+0.110
1N989B-1	150	142.5	157.5	0.85	1500	6000	2.4	7.0	43	114	0.5	10	+0.110
1N990B-1	160	152.0	168.0	0.80	1700	6500	2.2	7.5	40	122	0.5	10	+0.110
1N991B-1	180	171.0	189.0	0.68	2200	7100	2.0	9.0	36	137	0.5	10	+0.110
1N992B-1	200	190.0	210.0	0.65	2500	8000	1.8	12.0	32	152	0.5	10	+0.110

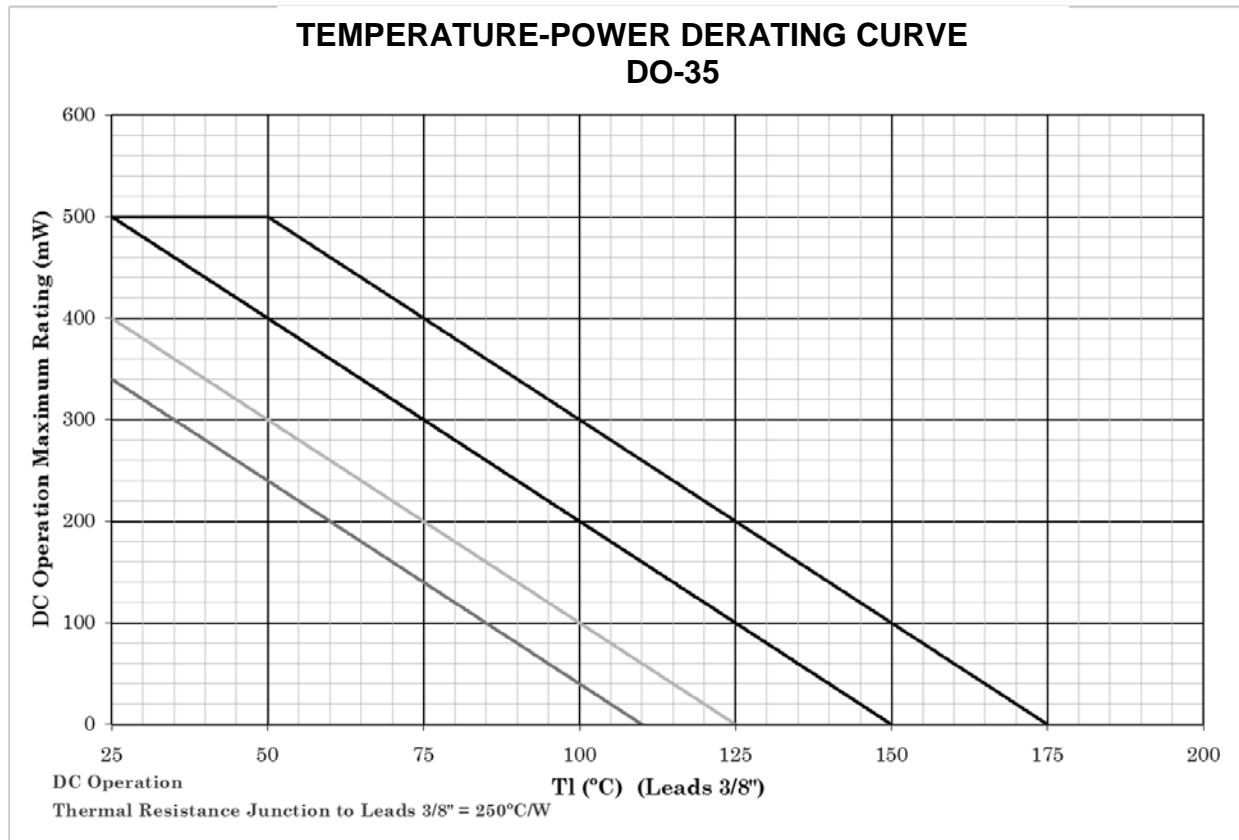


TABLE IV. Electrical characteristics (2 percent tolerance diodes) - Continued.

Col 1	Col 2	Col 3	Col 4	Col 5	Col 6	Col 7	Col 8	Col 9	Col 10	Col 11	Col 12	Col 13	Col 14
Type	V <sub>Z</sub> nom	V <sub>Z</sub> min	V <sub>Z</sub> max	I <sub>Z1</sub>	Z <sub>Z</sub>	Z <sub>ZK</sub>	I <sub>ZM</sub>	$\Delta V_Z$	I <sub>ZSM</sub>	V <sub>R</sub>	I <sub>R1</sub> at T <sub>A</sub> = +25°C V <sub>R</sub> = col 11	I <sub>R2</sub> at T <sub>A</sub> = +150°C V <sub>R</sub> = col 11	$\alpha V_Z$
	Volts	Volts	Volts	mA	ohms	ohms	mA	Volts	mA	Volts	$\mu A$	$\mu A$	%°C
1N962C-1	11	10.78	11.22	11.5	9.5	700	35	0.50	590	8.4	1.0	10	+0.073
1N963C-1	12	11.76	12.24	10.5	11.5	700	32	0.55	540	9.1	1.0	10	+0.076
1N964C-1	13	12.74	13.25	9.5	13.0	700	30	0.60	500	9.9	0.5	10	+0.079
1N965C-1	15	14.70	15.30	8.5	16.0	700	26	0.70	433	11	0.5	10	+0.082
1N966C-1	16	15.68	16.32	7.8	17.0	700	25	0.75	406	12	0.5	10	+0.083
1N967C-1	18	17.64	18.36	7.0	21	750	21	0.85	361	14	0.5	10	+0.085
1N968C-1	20	19.60	20.40	6.2	25	750	19	0.95	325	15	0.5	10	+0.086
1N969C-1	22	21.56	22.44	5.6	29	750	17	1.05	295	17	0.5	10	+0.087
1N970C-1	24	23.52	24.48	5.2	33	750	16	1.15	271	18	0.5	10	+0.088
1N971C-1	27	26.46	27.54	4.6	41	750	14	1.30	240	21	0.5	10	+0.090
1N972C-1	30	29.40	30.60	4.2	49	1000	13	1.45	216	23	0.5	10	+0.091
1N973C-1	33	32.34	33.66	3.8	58	1000	12	1.60	197	25	0.5	10	+0.092
1N974C-1	36	35.28	36.72	3.4	70	1000	11	1.75	180	27	0.5	10	+0.093
1N975C-1	39	38.22	39.78	3.2	80	1000	9.1	1.90	166	30	0.5	10	+0.094
1N976C-1	43	42.14	43.86	3.0	93	1000	8.8	2.10	151	33	0.5	10	+0.095
1N977C-1	47	46.06	47.94	2.7	105	1500	7.9	2.25	138	36	0.5	10	+0.096
1N978C-1	51	49.98	52.02	2.5	125	1500	7.4	2.5	127	39	0.5	10	+0.097
1N979C-1	56	54.88	57.12	2.2	150	2000	6.9	2.7	116	43	0.5	10	+0.096
1N980C-1	62	60.76	63.24	2.0	185	2000	6.0	2.9	105	47	0.5	10	+0.097
1N981C-1	68	66.64	69.36	1.8	230	2000	5.5	3.2	95	52	0.5	10	+0.097
1N982C-1	75	73.50	76.50	1.7	270	2000	5.1	3.4	86	56	0.5	10	+0.098
1N983C-1	82	80.36	83.64	1.5	330	3000	4.6	3.8	79	62	0.5	10	+0.098
1N984C-1	91	89.18	92.82	1.4	400	3000	4.2	4.2	71	69	0.5	10	+0.099
1N985C-1	100	98.0	102.0	1.3	500	3000	3.7	4.4	65	76	0.5	10	+0.110
1N986C-1	110	107.8	112.2	1.1	750	4000	3.3	4.8	59	84	0.5	10	+0.110
1N987C-1	120	117.6	122.4	1.0	900	4500	3.1	5.2	54	91	0.5	10	+0.110
1N988C-1	130	127.4	132.6	0.95	1100	5000	2.7	5.6	50	99	0.5	10	+0.110
1N989C-1	150	147.0	153.0	0.85	1500	6000	2.4	7.0	43	114	0.5	10	+0.110
1N990C-1	160	156.8	163.2	0.80	1700	6500	2.2	7.5	40	122	0.5	10	+0.110
1N991C-1	180	176.4	183.6	0.68	2200	7100	2.0	9.0	36	137	0.5	10	+0.110
1N992C-1	200	196.0	204.0	0.65	2500	8000	1.8	12.0	32	152	0.5	10	+0.110

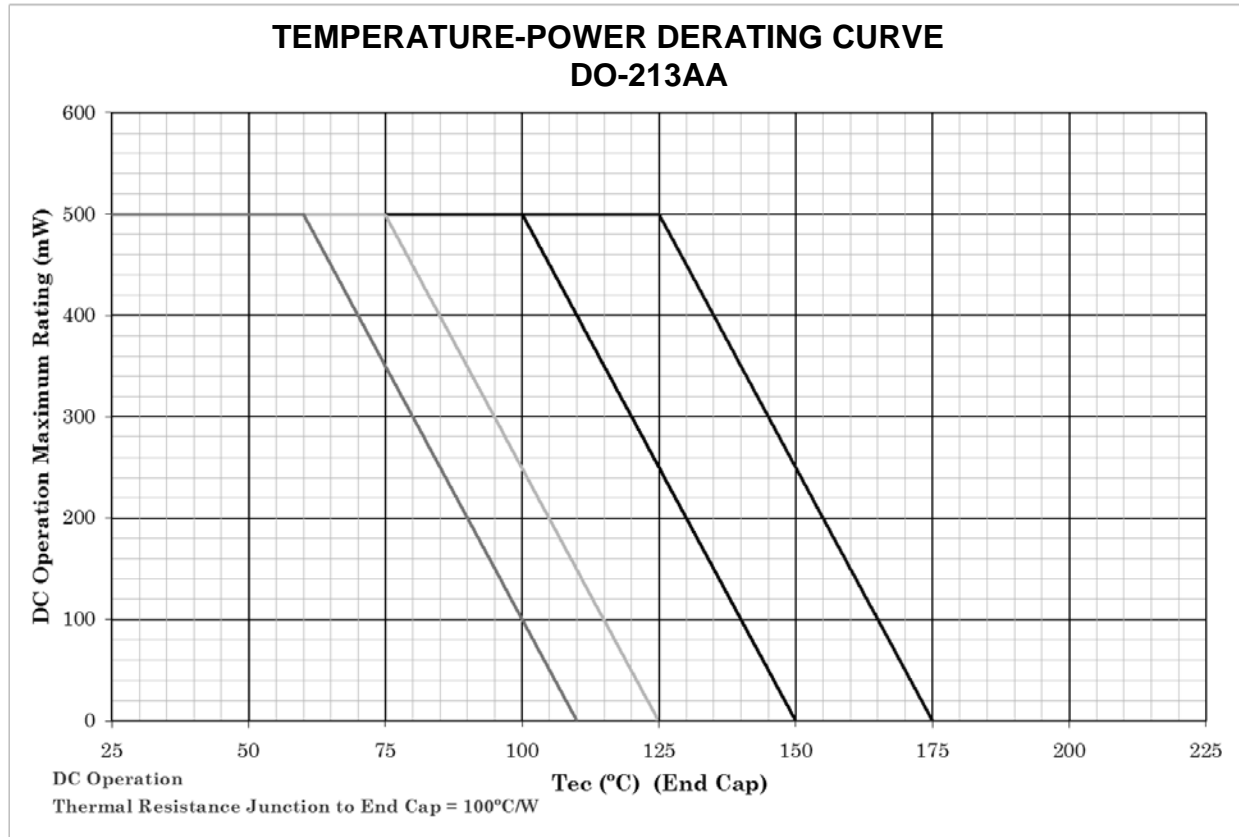
TABLE IV. Electrical characteristics (1 percent tolerance diodes) – Continued.

Col 1	Col 2	Col 3	Col 4	Col 5	Col 6	Col 7	Col 8	Col 9	Col 10	Col 11	Col 12	Col 13	Col 14
Type	VZ nom	VZ min	VZ max	I <sub>Z1</sub>	ZZ	ZZK	I <sub>ZM</sub>	ΔVZ	I <sub>ZSM</sub>	V <sub>R</sub>	I <sub>R1</sub> at T <sub>A</sub> = +25°C V <sub>R</sub> = col 11	I <sub>R2</sub> at T <sub>A</sub> = +150°C V <sub>R</sub> = col 11	αVZ
	Volts	Volts	Volts	mA	ohms	ohms	mA	Volts	mA	Volts	μA	μA	%/°C
1N962D-1	11	10.89	11.11	11.5	9.5	700	35	0.50	590	8.4	1.0	10	+0.073
1N963D-1	12	11.88	12.12	10.5	11.5	700	32	0.55	540	9.1	1.0	10	+0.076
1N964D-1	13	12.87	13.13	9.5	13.0	700	30	0.60	500	9.9	0.5	10	+0.079
1N965D-1	15	14.85	15.15	8.5	16.0	700	26	0.70	433	11	0.5	10	+0.082
1N966D-1	16	15.84	16.16	7.8	17.0	700	25	0.75	406	12	0.5	10	+0.083
1N967D-1	18	17.82	18.18	7.0	21	750	21	0.85	361	14	0.5	10	+0.085
1N968D-1	20	19.80	20.20	6.2	25	750	19	0.95	325	15	0.5	10	+0.086
1N969D-1	22	21.78	22.22	5.6	29	750	17	1.05	295	17	0.5	10	+0.087
1N970D-1	24	23.76	24.24	5.2	33	750	16	1.15	271	18	0.5	10	+0.088
1N971D-1	27	26.73	27.27	4.6	41	750	14	1.30	240	21	0.5	10	+0.090
1N972D-1	30	29.70	30.30	4.2	49	1000	13	1.45	216	23	0.5	10	+0.091
1N973D-1	33	32.67	33.33	3.8	58	1000	12	1.60	197	25	0.5	10	+0.092
1N974D-1	36	35.64	36.36	3.4	70	1000	11	1.75	180	27	0.5	10	+0.093
1N975D-1	39	38.61	39.39	3.2	80	1000	9.1	1.90	166	30	0.5	10	+0.094
1N976D-1	43	42.57	43.43	3.0	93	1000	8.8	2.10	151	33	0.5	10	+0.095
1N977D-1	47	46.53	47.47	2.7	105	1500	7.9	2.25	138	36	0.5	10	+0.095
1N978D-1	51	50.49	51.51	2.5	125	1500	7.4	2.5	127	39	0.5	10	+0.096
1N979D-1	56	55.44	56.56	2.2	150	2000	6.9	2.7	116	43	0.5	10	+0.096
1N980D-1	62	61.38	62.62	2.0	185	2000	6.0	2.9	105	47	0.5	10	+0.097
1N981D-1	68	67.32	68.68	1.8	230	2000	5.5	3.2	95	52	0.5	10	+0.097
1N982D-1	75	74.25	75.75	1.7	270	2000	5.1	3.4	86	56	0.5	10	+0.098
1N983D-1	82	81.18	82.82	1.5	330	3000	4.6	3.8	79	62	0.5	10	+0.098
1N984D-1	91	90.09	91.91	1.4	400	3000	4.2	4.2	71	69	0.5	10	+0.099
1N985D-1	100	99.0	101.0	1.3	500	3000	3.7	4.4	65	76	0.5	10	+0.110
1N986D-1	110	108.9	111.1	1.1	750	4000	3.3	4.8	59	84	0.5	10	+0.110
1N987D-1	120	118.8	121.2	1.0	900	4500	3.1	5.2	54	91	0.5	10	+0.110
1N988D-1	130	128.7	131.3	0.95	1100	5000	2.7	5.6	50	99	0.5	10	+0.110
1N989D-1	150	148.5	151.5	0.85	1500	6000	2.4	7.0	43	114	0.5	10	+0.110
1N990D-1	160	158.4	161.6	0.80	1700	6500	2.2	7.5	40	122	0.5	10	+0.110
1N991D-1	180	178.2	181.8	0.68	2200	7100	2.0	9.0	36	137	0.5	10	+0.110
1N992D-1	200	198.0	202.0	0.65	2500	8000	1.8	12.0	32	152	0.5	10	+0.110

**NOTES:**

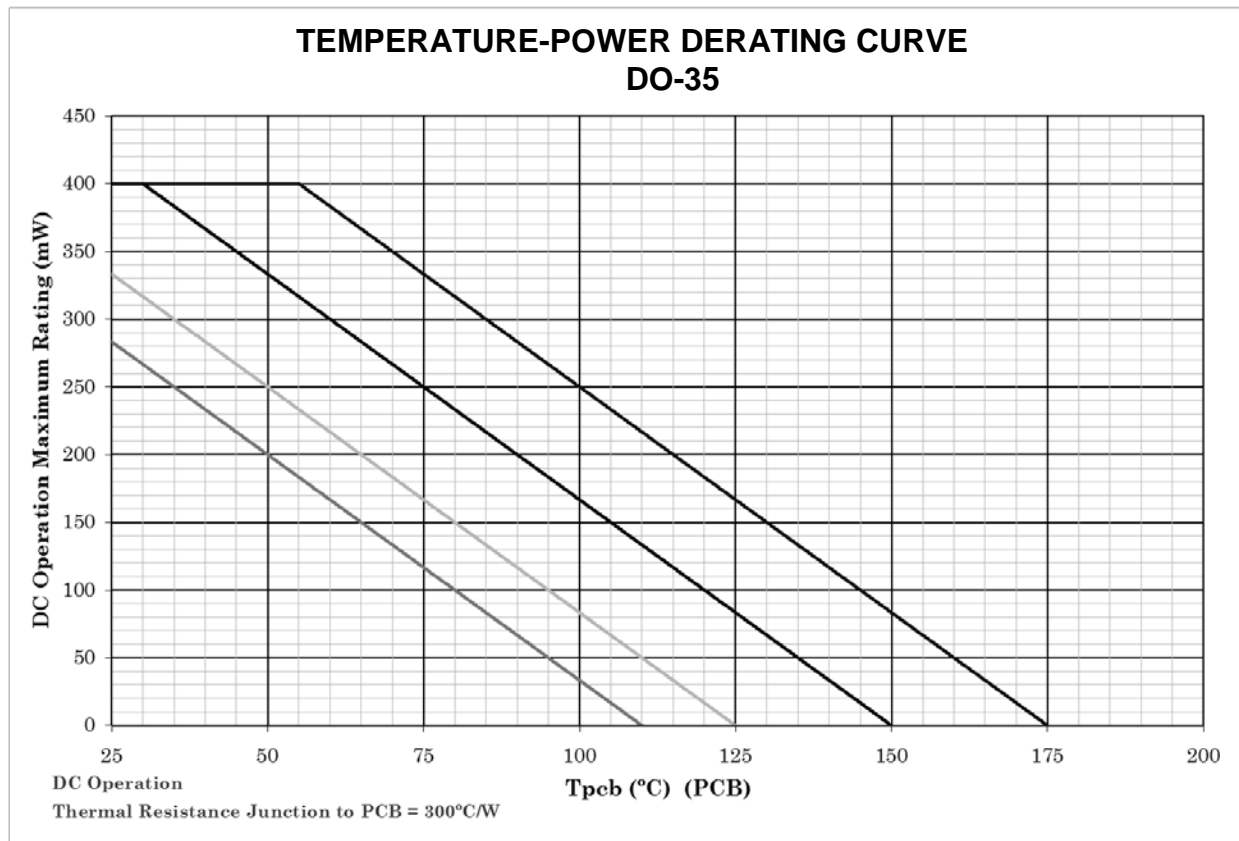
1. All devices are capable of operating at  $\leq T_J$  specified on this curve. Any parallel line to this curve will intersect the appropriate power for the desired maximum  $T_J$  allowed.
2. Derate design curve constrained by the maximum junction temperature ( $T_J \leq 175^\circ\text{C}$ ) and power rating specified. (See 1.3 herein.)
3. Derate design curve chosen at  $T_J \leq 150^\circ\text{C}$ , where the maximum temperature of electrical test is performed.
4. Derate design curves chosen at  $T_J \leq 125^\circ\text{C}$ , and  $110^\circ\text{C}$  to show power rating where most users want to limit  $T_J$  in their application.

FIGURE 5. Temperature-power derating curve.

**NOTES:**

1. All devices are capable of operating at  $\leq T_J$  specified on this curve. Any parallel line to this curve will intersect the appropriate power for the desired maximum  $T_J$  allowed.
2. Derate design curve constrained by the maximum junction temperature ( $T_J \leq 175^\circ\text{C}$ ) and power rating specified. (See 1.3 herein.)
3. Derate design curve chosen at  $T_J \leq 150^\circ\text{C}$ , where the maximum temperature of electrical test is performed.
4. Derate design curves chosen at  $T_J \leq 125^\circ\text{C}$ , and  $110^\circ\text{C}$  to show power rating where most users want to limit  $T_J$  in their application.

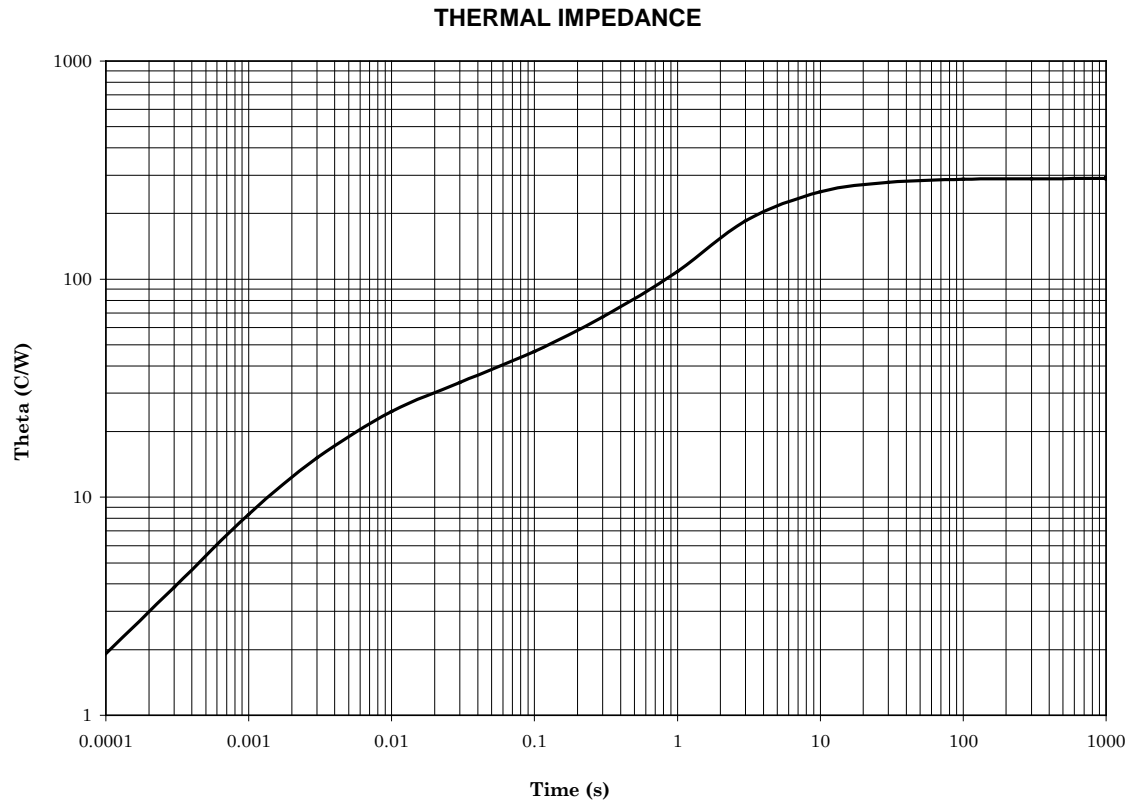
FIGURE 6. Temperature-power derating curve.



## NOTES:

1. All devices are capable of operating at  $\leq T_J$  specified on this curve. Any parallel line to this curve will intersect the appropriate power for the desired maximum  $T_J$  allowed.
2. Derate design curve constrained by the maximum junction temperature ( $T_J \leq 175^\circ\text{C}$ ) and power rating specified. (See 1.3 herein.)
3. Derate design curve chosen at  $T_J \leq 150^\circ\text{C}$ , where the maximum temperature of electrical test is performed.
4. Derate design curves chosen at  $T_J \leq 125^\circ\text{C}$ , and  $110^\circ\text{C}$  to show power rating where most users want to limit  $T_J$  in their application.

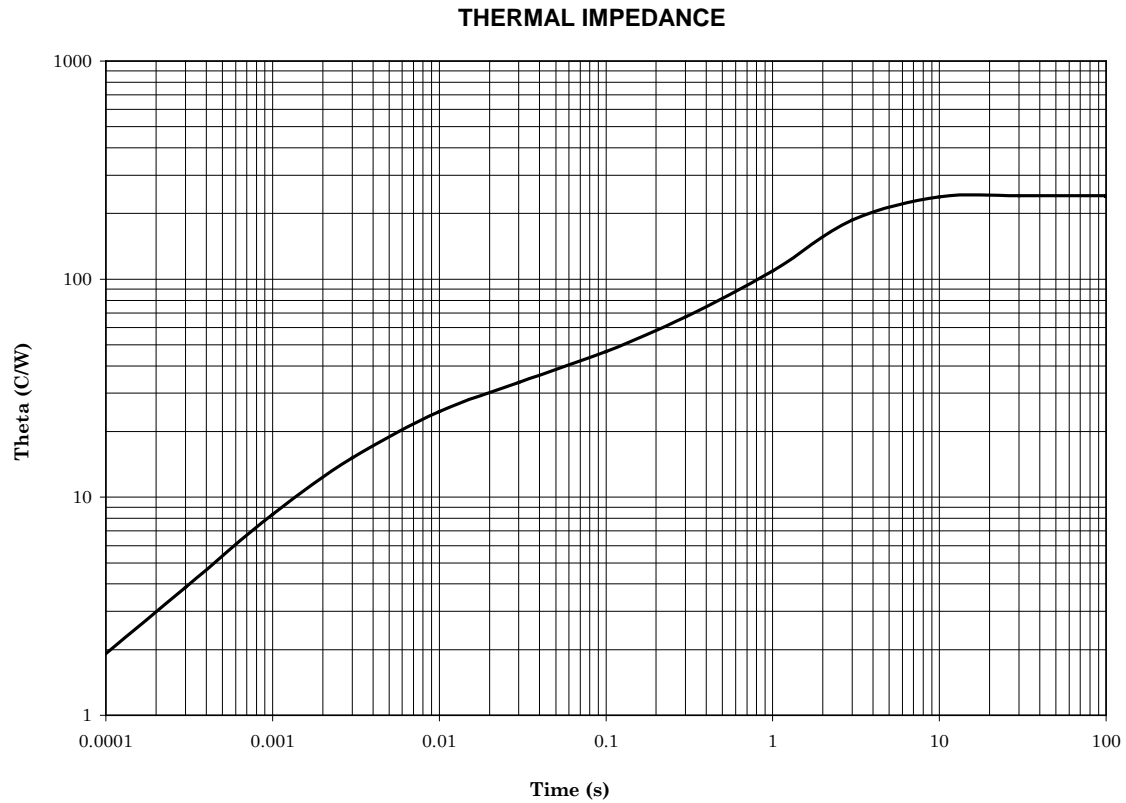
FIGURE 7. Temperature-power derating curve.



Thermal impedance DO-35 PCB mount, FR4, 1oz Cu, 50x87 mil pad (MELF) and 92 mil diameter (axial with .125 inch (3.175 mm) lead length) at  $T_A = 25^\circ\text{C}$ .

NOTE: Thermal resistance =  $300^\circ\text{C/W}$ . Maximum power rating = 400 mW at  $T_A = 55^\circ\text{C}$ .

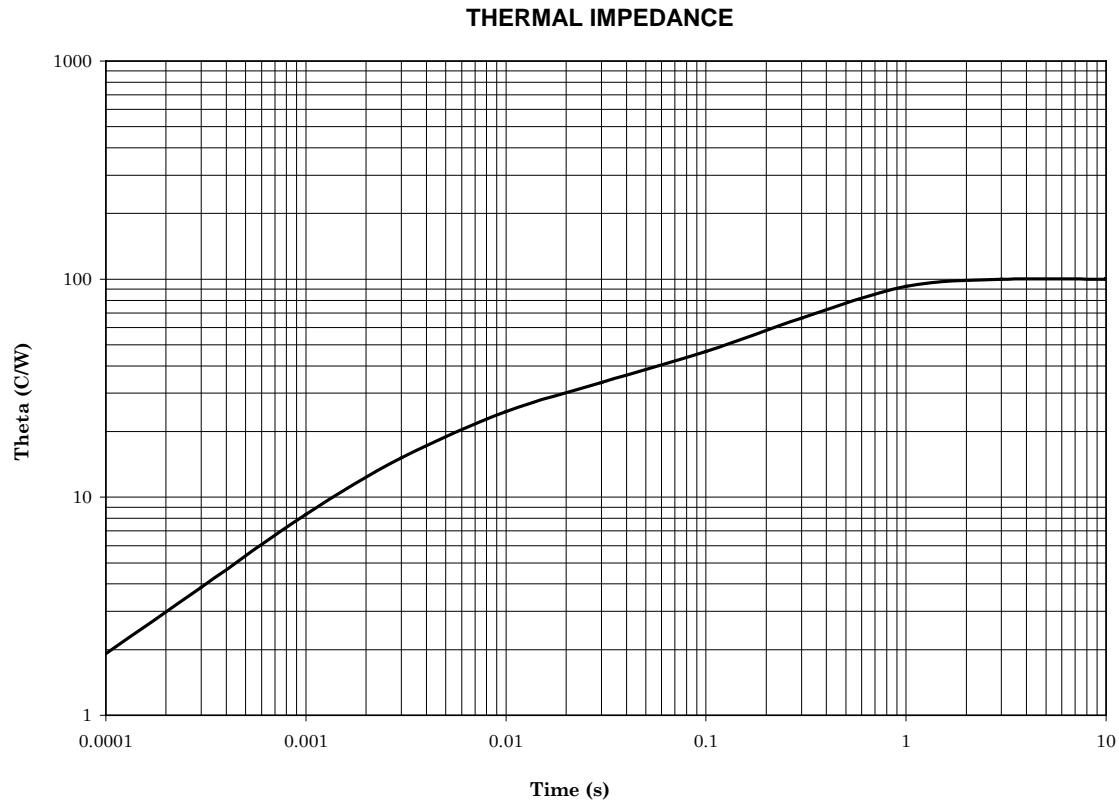
FIGURE 8. Thermal impedance DO-35 PCB mount.



Thermal impedance DO-35 axial,  $T_J = 25^\circ\text{C}$  at .375 inch (9.52 mm) from body.

NOTE: Thermal resistance =  $250^\circ\text{C/W}$ . Maximum power rating = 500 mW at  $T_L = 50^\circ\text{C}$ .

FIGURE 9. Thermal impedance DO-35 axial.

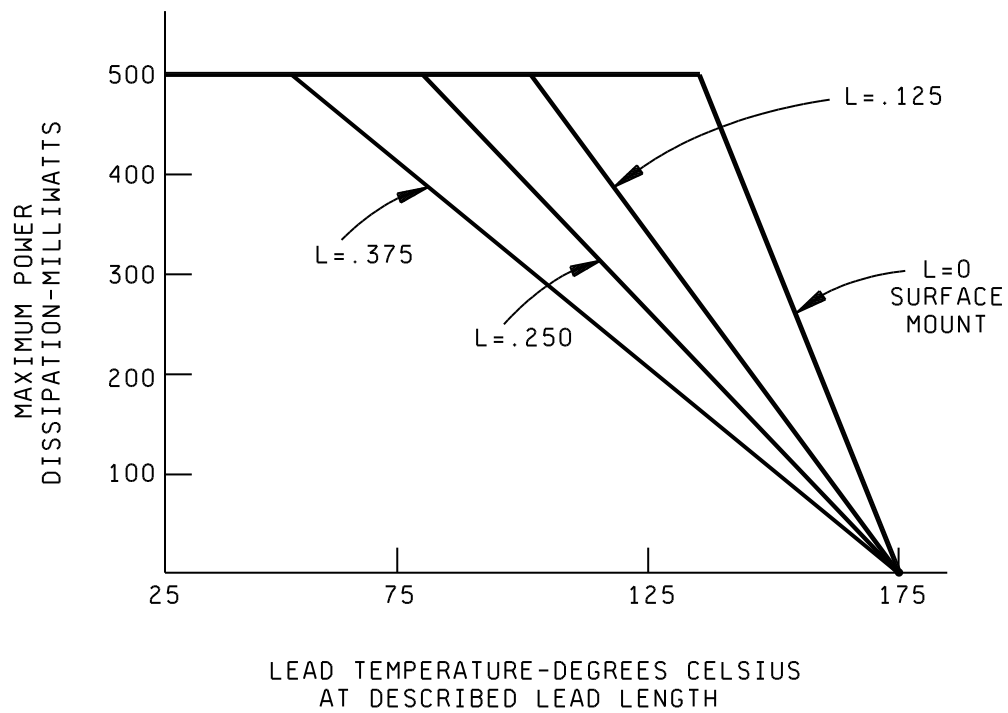


Thermal impedance DO-213AA MELF,  $T_{EC}=25^{\circ}\text{C}$ .

NOTE: Thermal resistance =  $100^{\circ}\text{C/W}$ . Power rating = 500 mW at  $T_{EC}=125^{\circ}\text{C}$ .

FIGURE 10. Thermal impedance DO-213AA MELF.





Inches	Millimeters
.000	0.00
.125	3.18
.250	6.35
.375	9.53

FIGURE 11. Maximum power versus lead temperature and lead length.

## 5. PACKAGING

5.1 Packaging. For acquisition purposes, the packaging requirements shall be as specified in the contract or order (see 6.2). When packaging of materiel is to be performed by DoD or in-house contractor personnel, these personnel need to contact the responsible packaging activity to ascertain packaging requirements. Packaging requirements are maintained by the Inventory Control Point's packaging activities within the Military Service or Defense Agency, or within the Military Service's system commands. Packaging data retrieval is available from the managing Military Department's or Defense Agency's automated packaging files, CD-ROM products, or by contacting the responsible packaging activity.

## 6. NOTES

(This section contains information of a general or explanatory nature that may be helpful, but is not mandatory. The notes specified in [MIL-PRF-19500](#) are applicable to this specification.)

6.1 Intended use. Semiconductors conforming to this specification are intended for original equipment design applications and logistic support of existing equipment.

6.2 Acquisition requirements. Acquisition documents should specify the following:

- a. Title, number, and date of this specification.
- b. Packaging requirements (see [5.1](#)).
- c. Lead finish (see [3.4.1](#)).
- d. Product assurance level and type designator.
- \* e. The complete Part or Identifying Number (PIN), see [1.5](#).

6.3 Qualification. With respect to products requiring qualification, awards will be made only for products which are, at the time of award of contract, qualified for inclusion in Qualified Manufacturers List ([QML-19500](#)) whether or not such products have actually been so listed by that date. The attention of the contractors is called to these requirements, and manufacturers are urged to arrange to have the products that they propose to offer to the Federal Government tested for qualification in order that they may be eligible to be awarded contracts or orders for the products covered by this specification. Information pertaining to qualification of products may be obtained from DLA Land and Maritime, VQE, P.O. Box 3990, Columbus, OH 43216-5000 or e-mail [vqe.chief@dla.mil](mailto:vqe.chief@dla.mil). An online listing of products qualified to this specification may be found in the Qualified Products Database (QPD) at <https://assist.dla.mil>.

6.4 Cross reference substitution list. JANS level will no longer be built to MIL-PRF-19500/117. Devices in stock are acceptable provided the date code does not exceed the date of 8 September 1997. Devices required for space flight applications will meet the requirements of MIL-PRF-19500/533. Existing supplies of parts can be used until existing supplies are exhausted. A PIN for PIN replacement table follows, and these devices are directly interchangeable:

JANS superseded PIN	JANS superseding PIN	JANS superseded PIN	JANS superseding PIN
1N962B-1	1N6325	1N978B-1	1N6341
1N963B-1	1N6326	1N979B-1	1N6342
1N964B-1	1N6327	1N980B-1	1N6343
1N965B-1	1N6328	1N981B-1	1N6344
1N966B-1	1N6329	1N982B-1	1N6345
1N967B-1	1N6330	1N983B-1	1N6346
1N968B-1	1N6331	1N984B-1	1N6347
1N969B-1	1N6332	1N985B-1	1N6348
1N970B-1	1N6333	1N986B-1	1N6349
1N971B-1	1N6334	1N987B-1	1N6350
1N972B-1	1N6335	1N988B-1	1N6351
1N973B-1	1N6336	1N989B-1	1N6352
1N974B-1	1N6337	1N990B-1	1N6353
1N975B-1	1N6338	1N991B-1	1N6354
1N976B-1	1N6339	1N992B-1	1N6355
1N977B-1	1N6340		

6.4.1 Substitutability of dash one parts. Non-dash-one devices have been deleted from this specification. Dash-one devices are a direct substitute for non dash-one devices and are preferred. The following table shows the direct substitutability. This is for all quality levels and tolerances.

Superseded PIN	Superseding PIN	Superseded PIN	Superseding PIN
1N962B	1N962B-1	1N978B	1N978B-1
1N963B	1N963B-1	1N979B	1N979B-1
1N964B	1N964B-1	1N980B	1N980B-1
1N965B	1N965B-1	1N981B	1N981B-1
1N966B	1N966B-1	1N982B	1N982B-1
1N967B	1N967B-1	1N983B	1N983B-1
1N968B	1N968B-1	1N984B	1N984B-1
1N969B	1N969B-1	1N985B	1N985B-1
1N970B	1N970B-1	1N986B	1N986B-1
1N971B	1N971B-1	1N987B	1N987B-1
1N972B	1N972B-1	1N988B	1N988B-1
1N973B	1N973B-1	1N989B	1N989B-1
1N974B	1N974B-1	1N990B	1N990B-1
1N975B	1N975B-1	1N991B	1N991B-1
1N976B	1N976B-1	1N992B	1N992B-1
1N977B	1N977B-1		

6.4.2 Substitutability of 2 percent and 1 percent tolerance devices. Devices of tighter tolerance are a direct one-way substitute for the looser tolerance devices (example: JANTX1N964D-1 substitutes for JANTX1N964B-1).

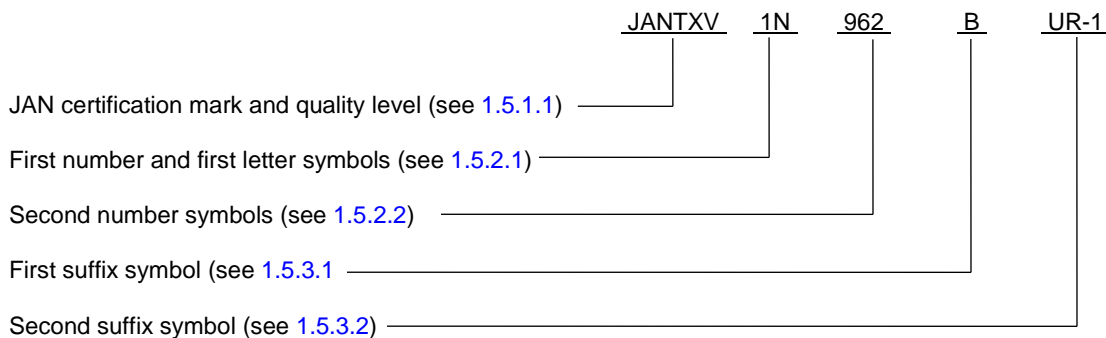
\* 6.5 Suppliers of JANHC and JANKC die. The qualified JANHC and JANKC die suppliers with the applicable letter version (example JANHCA1N4370A) will be identified on the QML.

JANHC ordering information (1) (2)				
PIN	Manufacture CAGE			
	43611	12954	52GC4	13409
1N962B	JANHCA1N962B	JANHCB1N962B	JANHCC1N962B	JANHCD1N962B
1N963B	JANHCA1N963B	JANHCB1N963B	JANHCC1N963B	JANHCD1N963B
1N964B	JANHCA1N964B	JANHCB1N964B	JANHCC1N964B	JANHCD1N964B
1N965B	JANHCA1N965B	JANHCB1N965B	JANHCC1N965B	JANHCD1N965B
1N966B	JANHCA1N966B	JANHCB1N966B	JANHCC1N966B	JANHCD1N966B
1N967B	JANHCA1N967B	JANHCB1N967B	JANHCC1N967B	JANHCD1N967B
1N968B	JANHCA1N968B	JANHCB1N968B	JANHCC1N968B	JANHCD1N968B
1N969B	JANHCA1N969B	JANHCB1N969B	JANHCC1N969B	JANHCD1N969B
1N970B	JANHCA1N970B	JANHCB1N970B	JANHCC1N970B	JANHCD1N970B
1N971B	JANHCA1N971B	JANHCB1N971B	JANHCC1N971B	JANHCD1N971B
1N972B	JANHCA1N972B	JANHCB1N972B	JANHCC1N972B	JANHCD1N972B
1N973B	JANHCA1N973B	JANHCB1N973B	JANHCC1N973B	JANHCD1N973B
1N974B	JANHCA1N974B	JANHCB1N974B	JANHCC1N974B	JANHCD1N974B
1N975B	JANHCA1N975B	JANHCB1N975B	JANHCC1N975B	JANHCD1N975B
1N976B	JANHCA1N976B	JANHCB1N976B	JANHCC1N976B	JANHCD1N976B
1N977B	JANHCA1N977B	JANHCB1N977B	JANHCC1N977B	JANHCD1N977B
1N978B	JANHCA1N978B	JANHCB1N978B	JANHCC1N978B	JANHCD1N978B
1N979B	JANHCA1N979B	JANHCB1N979B	JANHCC1N979B	JANHCD1N979B
1N980B	JANHCA1N980B	JANHCB1N980B	JANHCC1N980B	JANHCD1N980B
1N981B	JANHCA1N981B	JANHCB1N981B	JANHCC1N981B	JANHCD1N981B
1N982B	JANHCA1N982B	JANHCB1N982B	JANHCC1N982B	JANHCD1N982B
1N983B	JANHCA1N983B	JANHCB1N983B	JANHCC1N983B	JANHCD1N983B
1N984B	JANHCA1N984B	JANHCB1N984B	JANHCC1N984B	JANHCD1N984B
1N985B	JANHCA1N985B	JANHCB1N985B	JANHCC1N985B	JANHCD1N985B
1N986B	JANHCA1N986B	JANHCB1N986B	JANHCC1N986B	JANHCD1N986B
1N987B	JANHCA1N987B	JANHCB1N987B	JANHCC1N987B	JANHCD1N987B
1N988B	JANHCA1N988B	JANHCB1N988B	JANHCC1N988B	JANHCD1N988B
1N989B	JANHCA1N989B	JANHCB1N989B	JANHCC1N989B	JANHCD1N989B
1N990B	JANHCA1N990B	JANHCB1N990B	JANHCC1N990B	JANHCD1N990B
1N991B	JANHCA1N991B	JANHCB1N991B	JANHCC1N991B	JANHCD1N991B
1N992B	JANHCA1N992B	JANHCB1N992B	JANHCC1N992B	JANHCD1N992B

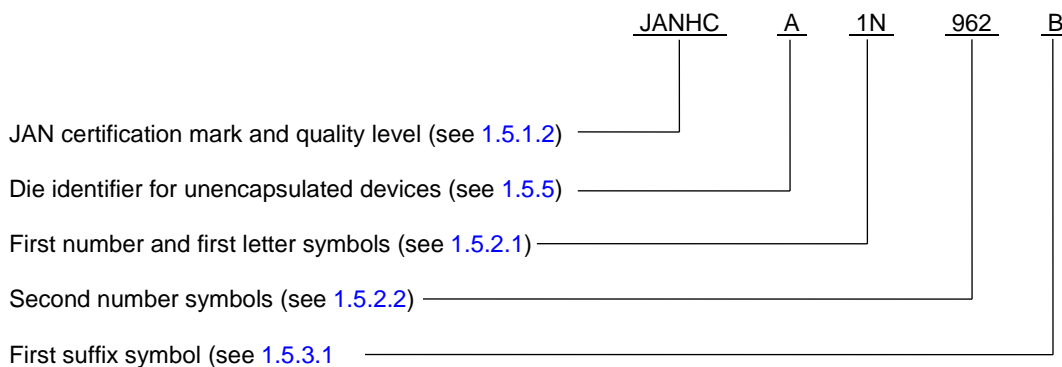
- (1) Applies to "C" and "D" suffix versions also. Replace all "B" suffixes with "C" or "D" as applicable for correct PIN.  
 (2) For JANKC level, replace JANHC with JANKC.

\* 6.6 PIN construction example.

\* 6.6.1 Encapsulated devices The PINs for encapsulated devices are constructed using the following form.



\* 6.6.2 Unencapsulated devices. The PINs for un-encapsulated devices are constructed using the following form.



\* 6.7 List of PINs. The following is a list of possible PINs available on this specification sheet.

\* 6.7.1 List of Encapsulated device types.

PINs for type 1N962B-1 through 1N992B-1. 1/	
JAN1N962B-1 through JAN1N992B-1	JANTXV1N962B-1 through JANTXV1N992B-1
JAN1N962BUR-1 through JAN1N992BUR-1	JANTXV1N962BUR-1 through JANTXV1N992BUR-1
JAN1N962C-1 through JAN 1N992C-1	JANTXV1N962C-1 through JANTXV1N992C-1
JAN1N962CUR-1 through JAN1N992CUR-1	JANTXV1N962CUR-1 through JANTXV1N992CUR-1
JAN1N962D-1 through JAN1N992D-1	JANTXV1N962D-1 through JANTXV1N992D-1
JAN1N962DUR-1 through JAN1N992DUR-1	JANTXV1N962DUR-1 through JANTXV1N992DUR-1
JANTX1N962B-1 through JANTX1N992B-1	
JANTX1N962BUR-1 through JANTX1N992BUR-1	
JANTX1N962C-1 through JANTX1N992C-1	
JANTX1N962CUR-1 through JANTX1N992CUR-1	
JANTX1N962D-1 through JANTX1N992D-1	
JANTX1N962DUR-1 through JANTX1N992DUR-1	

1/ see 6.4

\* 6.7.2 List of Unencapsulated device types.

JANHCA1N962B	JANHCB1N962B	JANHCC1N962B	JANHCD1N962B
JANHCA1N963B	JANHCB1N963B	JANHCC1N963B	JANHCD1N963B
JANHCA1N964B	JANHCB1N964B	JANHCC1N964B	JANHCD1N964B
JANHCA1N965B	JANHCB1N965B	JANHCC1N965B	JANHCD1N965B
JANHCA1N966B	JANHCB1N966B	JANHCC1N966B	JANHCD1N966B
JANHCA1N967B	JANHCB1N967B	JANHCC1N967B	JANHCD1N967B
JANHCA1N968B	JANHCB1N968B	JANHCC1N968B	JANHCD1N968B
JANHCA1N969B	JANHCB1N969B	JANHCC1N969B	JANHCD1N969B
JANHCA1N970B	JANHCB1N970B	JANHCC1N970B	JANHCD1N970B
JANHCA1N971B	JANHCB1N971B	JANHCC1N971B	JANHCD1N971B
JANHCA1N972B	JANHCB1N972B	JANHCC1N972B	JANHCD1N972B
JANHCA1N973B	JANHCB1N973B	JANHCC1N973B	JANHCD1N973B
JANHCA1N974B	JANHCB1N974B	JANHCC1N974B	JANHCD1N974B
JANHCA1N975B	JANHCB1N975B	JANHCC1N975B	JANHCD1N975B
JANHCA1N976B	JANHCB1N976B	JANHCC1N976B	JANHCD1N976B
JANHCA1N977B	JANHCB1N977B	JANHCC1N977B	JANHCD1N977B
JANHCA1N978B	JANHCB1N978B	JANHCC1N978B	JANHCD1N978B
JANHCA1N979B	JANHCB1N979B	JANHCC1N979B	JANHCD1N979B
JANHCA1N980B	JANHCB1N980B	JANHCC1N980B	JANHCD1N980B
JANHCA1N981B	JANHCB1N981B	JANHCC1N981B	JANHCD1N981B
JANHCA1N982B	JANHCB1N982B	JANHCC1N982B	JANHCD1N982B
JANHCA1N983B	JANHCB1N983B	JANHCC1N983B	JANHCD1N983B
JANHCA1N984B	JANHCB1N984B	JANHCC1N984B	JANHCD1N984B
JANHCA1N985B	JANHCB1N985B	JANHCC1N985B	JANHCD1N985B
JANHCA1N986B	JANHCB1N986B	JANHCC1N986B	JANHCD1N986B
JANHCA1N987B	JANHCB1N987B	JANHCC1N987B	JANHCD1N987B
JANHCA1N988B	JANHCB1N988B	JANHCC1N988B	JANHCD1N988B
JANHCA1N989B	JANHCB1N989B	JANHCC1N989B	JANHCD1N989B
JANHCA1N990B	JANHCB1N990B	JANHCC1N990B	JANHCD1N990B
JANHCA1N991B	JANHCB1N991B	JANHCC1N991B	JANHCD1N991B
JANHCA1N992B	JANHCB1N992B	JANHCC1N992B	JANHCD1N992B

6.8 Maximum power versus lead temperature. Typical maximum power rating as a function of lead temperature for various lead lengths is shown on [figure 11](#).

\* 6.9 Changes from previous issue. The margins of this specification are marked with asterisks to indicate where changes from the previous issue were made. This was done as a convenience only and the Government assumes no liability whatsoever for any inaccuracies in these notations. Bidders and contractors are cautioned to evaluate the requirements of this document based on the entire content irrespective of the marginal notations.

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